

# Solid state physics 2019 Final Exam

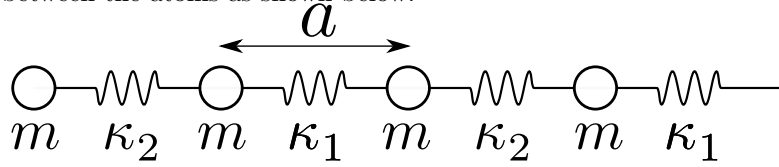
April 16th, 2019

Good luck!

- You may not use textbooks, notes, or calculators.
- When plotting, label the axes and mark the important values.
- If you need extra answer space: ask for an extra exam copy, fill in your name and continue writing the solution.

1. (35 points) **Band structure of phonons in 1D**

Consider a 1D chain of atoms of mass  $m$  connected by springs with alternating spring constants  $\kappa_1$  and  $\kappa_2$ , and a distance  $a$  between the atoms as shown below.



(a) (5 points) Write down the equations of motion for the atoms in a unit cell of this chain. Formulate the running wave ansatz for computing the dispersion relation.

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(b) (10 points) Find the dispersion relation by solving the equations of motion.

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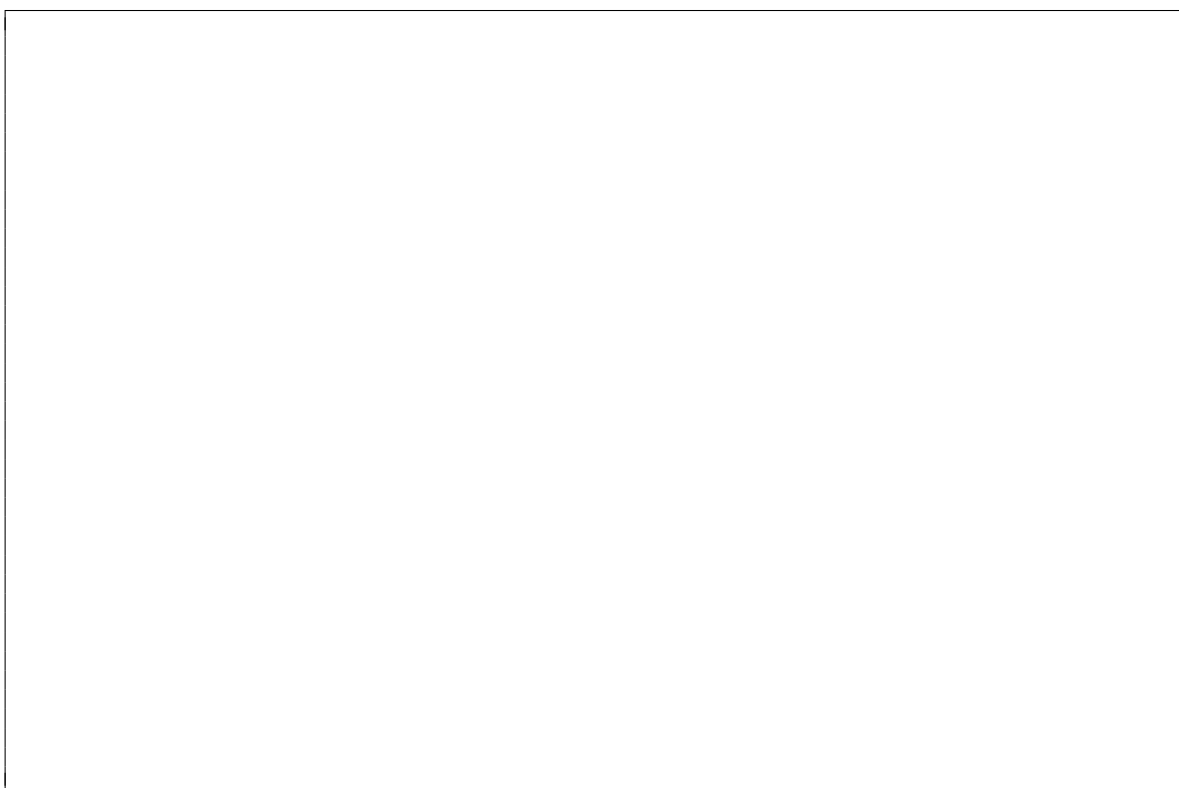
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- (c) (10 points) Sketch the dispersion relation  $\omega(k)$  and the density of states  $g(\omega)$  when the spring constants are close but not equal ( $\kappa_1 \approx \kappa_2$ ).



- (d) (10 points) Simplify the found dispersion relation of the optical and acoustic branches assuming  $\kappa_1 \gg \kappa_2$ . How does this approximate dispersion of the acoustic branch relate to that of a monatomic chain with only one spring constant? How can the dispersion of the optical branch be understood from the vibrational frequency spectrum of a single diatomic molecule? (If you did not derive the dispersion, try to compute what happens when  $\kappa_1 \gg \kappa_2$  directly.)

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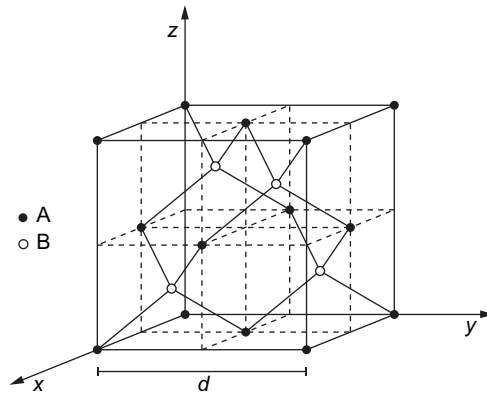
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2. (35 points) **Zinc-blende crystal structure**

Consider the Zinc-blende crystal structure shown below.



(a) (5 points) Give a set of primitive lattice vectors and the corresponding basis.

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(b) (10 points) Calculate the filling factor of this crystal, assuming that the atoms have equal radii  $r_A = r_B$ . For what ratio of  $r_B/r_A$  do you expect the filling fraction to be maximal?

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(c) (10 points) Calculate the reciprocal lattice vectors corresponding to the lattice vectors you formulated in (a). Calculate the volume of the primitive unit cell of the reciprocal lattice.

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(d) (10 points) Compute the structure factor  $S$  corresponding to the lattice vectors found in (a) (so the primitive lattice vectors). Use  $f_A$  and  $f_B$  as form factors for atoms A and B. Which diffraction peaks vanish when  $f_A = f_B$ ?

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3. (30 points) **A two-dimensional semiconductor**

Consider a **two-dimensional** semiconductor with a band gap  $E_G \gg k_B T$ . The effective electron mass at the bottom of the conduction band is  $m_e$ . The effective hole mass at the top of the valence band is  $m_h$ ,  $m_h > m_e$ . We put the zero of energy at the top of the valence band and consider the semiconductor to be in the intrinsic regime. The Fermi level is far from both bands, and we may assume Boltzmann distribution for electrons and holes.

(a) (10 points) Compute and sketch the density of states of this semiconductor.

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(b) (10 points) Calculate the concentration of holes  $n_h$  in the valence band as a function of the Fermi energy  $E_F$ , temperature  $T$ , and  $m_h$ . Also calculate the concentration of electrons  $n_e$  in the conduction band as a function of the Fermi energy  $E_F$ , temperature  $T$ , and  $m_e$ .

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(c) (5 points) Write down an expression for the electron heat capacity of this semiconductor as an integral over energies.

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(d) (5 points) Discuss whether the electron heat capacity becomes larger than the phonon heat capacity as temperature is lowered towards 0K.

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